

### Two Channel Differential 2:1/1:2 USB 3.1 Super Speed 10Gbps Mux/DeMux

### **Descriptions**

The FSW3410 is a high speed bidirectional passive switch in mux or demux configurations suited for USB Type-C™ application supporting USB 3.1 Gen 1 and Gen 2 data rates. Based on control pin SEL, the device provides switching on differential channels between Port A or Port B to Port COM. The FSW3410 is a generic analog differential passive switch that can work for any high speed interface applications requiring a common mode voltage range of 0 to 2 V and differential signaling with differential amplitude up to 1800 mVpp. It employs adaptive tracking that ensures the channel remains unchanged for the entire common mode voltage range. Excellent dynamic characteristics of the device allow high speed switching with minimum attenuation to the signal eye diagram with very little added jitter. It consumes <2mW of power when operational and has a shutdown mode exercisable by EN pin resulting <20uW.

#### **Features**

- 2-Differential Channel 1:2/2:1 Mux/DeMux
- USB 3.1 Super Speed 10Gbps Switch
- High Bandwidth: 5.1GHz @-3dB BW
- Supports both AC coupled and DC coupled signals
- Isolation: -40dB @ 2.0 Gbps
- Crosstalk: -31dB @ 2.0 Gbps
- ESD Tolerance: 2kV HBM
- Low bit-to-bit skew, Bidirectional
- Wide VCC Operating Range: 1.5V ~ 5.0V

#### **Applications**

- USB Type-C Ecosystem
- Desktop and Notebook PCs
- Server/Storage Area Networks
- PCI Express Backplanes
- Shared I/O Ports

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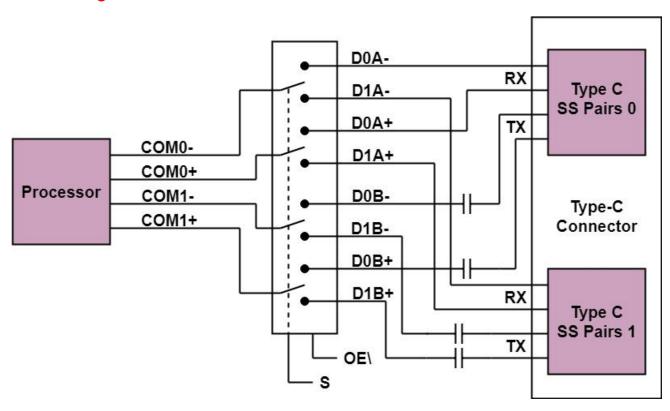
FPD LinkII and FPD LinkIII Switching



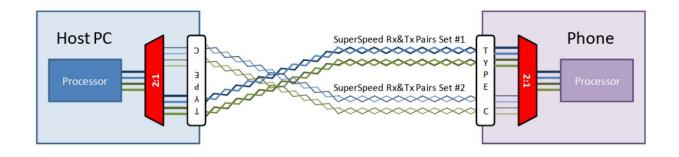
### Order information

| Mode    | Package        | Ordering Number   | Packing Option     |
|---------|----------------|-------------------|--------------------|
| FSW3410 | QFN2.8x2.0-18L | FSW3410YQFN18G/TR | Tape and Reel,5000 |

## **Block Diagram**

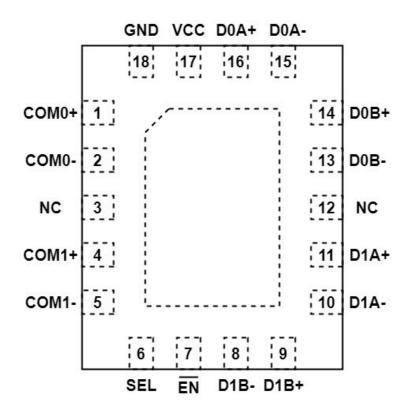


# **Typical Application**





# Pin Configuration



| Pin# | Pin Name | Signal Type Description |   |
|------|----------|-------------------------|---|
| 1    | COM0+    | I/O                     | Positive differential signal 0 for COM port |
| 2    | COM0-    | I/O                     | Negative differential signal 0 for COM port |
| 3    | NC       | /                       | Not Connected                               |
| 4    | COM1+    | I/O                     | Positive differential signal 1 for COM port |
| 5    | COM1-    | I/O                     | Negative differential signal 1 for COM port |
| 6    | SEL      | I                       | Select Pin, See Truth Table                 |
| 7    | EN       | I                       | Enable Pin, Active Low                      |
| 8    | D1B-     | I/O                     | Negative differential signal 1 for port B   |
| 9    | D1B+     | I/O                     | Positive differential signal 1 for port B   |
| 10   | D1A-     | I/O                     | Negative differential signal 1 for port A   |
| 11   | D1A+     | I/O                     | Positive differential signal 1 for port A   |
| 12   | NC       | /                       | Not Connected                               |
| 13   | D0B-     | I/O                     | Negative differential signal 0 for port B   |
| 14   | D0B+     | I/O                     | Positive differential signal 0 for port B   |
| 15   | D0A-     | I/O                     | Negative differential signal 0 for port A   |
| 16   | D0A+     | I/O                     | Positive differential signal 0 for port A   |
| 17   | VCC      | Power                   | Positive Supply Voltage                     |
| 18   | GND      | Ground                  | Power Ground                                |



#### **Truth Table**

| EN   | SEL  | COM0- | COM0+ | COM1- | COM1+ |
|------|------|-------|-------|-------|-------|
| High | X    | Hi-Z  | Hi-Z  | Hi-Z  | Hi-Z  |
| Low  | Low  | D0A-  | D0A+  | D0B-  | D0B+  |
| Low  | High | D1A-  | D1A+  | D1B-  | D1B+  |

# **Maximum Ratings**

(Above which useful life may be impaired. For user guidelines, not tested.)

| Storage Temperature                | -65°C to +150°C |
|------------------------------------|-----------------|
| Junction Temperature               | 125°C           |
| Supply Voltage to Ground Potential | -0.5V to +5.5V  |
| Supe Speed Data Channel TX / RX    | -0.5V to 3.8V   |
| DC Input Voltage                   | -0.5V to VCC    |
| DC Output Current                  | 50mA            |
| Power Dissipation                  | 300mW           |

Notes:

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

### **Electrical Characteristics**

(TA=25°C, VCC=1.8V, unless otherwise specified)

| Parameter                          | Symbol               | conditions  | Min. | Тур. | Max  | Unit      |
|------------------------------------|----------------------|---|------|------|------|-----------|
| POWER SUPPLY                       |                      |   |      |      |      |           |
| VCC Quiescent Current              | IQ                   | SEL=0 or VCC, _EN=0                                 |      | 28   |      | uA        |
| Power-down Current                 | $I_{PO}$             | SEL=0 or VCC, _EN=VCC                               |      |      | 1    | uA        |
| DC CHARACTERISTICS                 |                      |   |      |      |      |           |
| Input logic high                   | $V_{ m IH}$          | VCC=1.8~4.5V  | 1.6  |      |      | V         |
| Input logic low                    | V <sub>IL</sub>      | VCC=1.8~4.5V  |      |      | 0.4  | V         |
| _EN Internal pull-up resistor      | R <sub>UP</sub>      |   |      | 2    |      | $M\Omega$ |
| SEL Internal pull-down resistor    | R <sub>DN</sub>      |   |      | 2    |      | ΜΩ        |
| On-Resistancefor TX/RX             | R <sub>ON_HS</sub>   | $V_{IS}=0.2V~I_{ON}=8mA$                            |      | 6.7  | 8    | Ω         |
| Ron Flatness for TX/RX             | R <sub>FLAT_LP</sub> | V <sub>IS</sub> = 0 to 1.2V I <sub>ON</sub> =8mA    |      | 0.8  | 1    | Ω         |
| R <sub>ON</sub> Flatness for TX/RX | R <sub>FLAT_LP</sub> | V <sub>IS</sub> = 0 to 0.2V I <sub>ON</sub> =8mA    |      | 0.2  | 0.3  | Ω         |
| Ron Matching Between Channels      | RMATCH               | V <sub>IS</sub> = 0 to 1.2V I <sub>ON</sub> =8mA    |      | 0.1  |      | Ω         |
| Switch Off Leakage Current         | $I_{OFF}$            | EN =VCC,COM0,COM1=VCC<br>D0A,D1A,D0B,D1B=0          | -0.5 |      | 0.5  | uA        |
| AC CHARACTERISTICS                 |                      |   |      |      |      |           |
| Enable Time _EN to Output          | $t_{\rm EN}$         | $R_L$ =50 $\Omega$ $C_L$ =0pF $V_{IS}$ = 0.6 $V$    |      | 80   | 150  | uS        |
| Disable Time _EN to Output         | $t_{ m DIS}$         | $R_L=50\Omega$ $C_L=0$ pF $V_{IS}=0.6$ V            |      | 40   | 250  | nS        |
| Turn-On Time SEL to Output         | ton                  | $R_L$ =50 $\Omega$ $C_L$ =0pF $V_{IS}$ = 0.6 $V$    |      | 400  | 1200 | nS        |
| Turn-Off Time SEL to Output        | t <sub>OFF</sub>     | $R_L = 50\Omega \ C_L = 0pF \ V_{IS} = 0.6V$        |      | 130  | 800  | nS        |
| Break-Before-Make Time             | $t_{ m BBM}$         | $R_L$ =50 $\Omega$ $C_L$ =0pF $V_{IS}$ = 0.6 $V$    |      | 250  | 800  | nS        |
| Propagation Delay                  | t <sub>PD</sub>      | $R_L$ =50 $\Omega$ $C_L$ =0 $pF$ $V_{IS}$ = 0.6 $V$ |      | 0.25 |      | nS        |



| Off Isolation          | Off                | $R_L = 50\Omega \text{ f} = 1.2\text{GHz V}_{IS} = 0.2\text{V}_{PP}, \text{ See Fig.2}$  |     | -27 |  | dB  |
|------------------------|--------------------|--|-----|-----|--|-----|
| Crosstalk              | $X_{TALK}$         | $R_L = 50\Omega \text{ f} = 1.2\text{GHz V}_{IS} = 0.2\text{V}_{PP}, \text{ See Fig. 1}$ |     | -43 |  | dB  |
| -3dB Bandwidth         | BW <sub>-3dB</sub> | $R_L$ =50 $\Omega$ $C_L$ =0pF Signal 0dBm  | 4.5 | 5.1 |  | GHz |
| CAPACITANCE            |                    |  |     |     |  |     |
| Switch On Capacitance  | Con                | $V_{Bias} = 0.2V, f = 1.5GHz$  |     | 1.5 |  | pF  |
| Switch Off Capacitance | C <sub>OFF</sub>   | $V_{Bias} = 0.2V, f = 1.5GHz$  |     | 1.0 |  | pF  |

#### **Notes:**

- (1) Flatness is defined as the difference between maximum and minimum value of ON-resistance at the specified analog signal voltage points.
- (2)  $R_{ON}$  matching between channels is calculated by subtracting the channel with the lowest max Ron value from the channel with the highest max Ron value.
- (3) Crosstalk is inversely proportional to source impedance

# **Application Information**

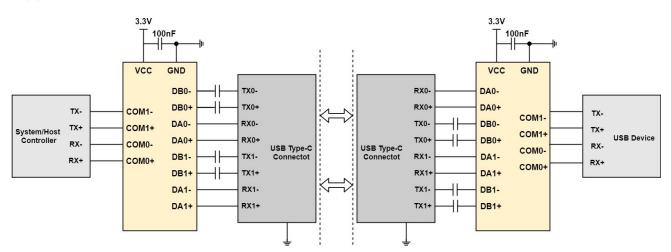
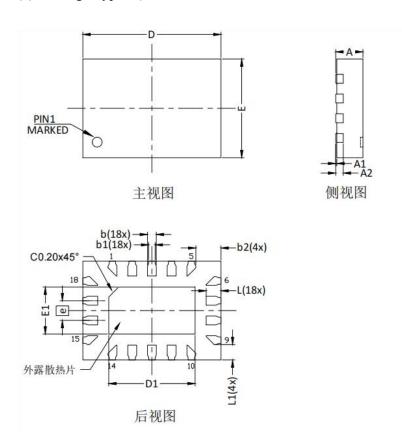


Fig. AC Coupling Capacitors for USB Type-C



# Package Outline Dimensions(All dimensions in mm.)

(1) Package Type: QFN2.8x2.0-18L



|        | DI       | MENSION(M | (4.4 |  |
|--------|----------|-----------|------|--|
| SYMBOL |          |           | ,    |  |
|        | MIN      | NOM       | MAX  |  |
| Α      | 0.50     | 0.55      | 0.60 |  |
| A1     | 0.00     |           | 0.05 |  |
| A2     | 0.152BSC |           |      |  |
| b      | 0.13     | 0.18      | 0.23 |  |
| b1     | 0.13REF  |           |      |  |
| b2     | 0.51REF  |           |      |  |
| D      | 2.70     | 2.80      | 2.90 |  |
| D1     | 1.70     | 1.75      | 1.80 |  |
| E      | 1.90     | 2.00      | 2.10 |  |
| E1     | 0.90     | 0.95      | 1.00 |  |
| е      | 0.40BSC  |           |      |  |
| L      | 0.20     | 0.30      | 0.40 |  |
| L1     |          | 0.31REF   |      |  |

### **Version Modification Record**

| Version Number | Revision                                  | Date      |
|----------------|---|-----------|
| first edition  |   | /         |
| V1.0           | 1. Update the order information on page 2 | 2024/07/5 |